

NSR0620P2

Schottky Barrier Diode

Schottky barrier diodes are optimized for very low forward voltage drop and low leakage current and are used in a wide range of dc-dc converter, clamping and protection applications in portable devices. NSR0620P2 in a SOD-923 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Very Low Forward Voltage Drop – 350 mV @ 100 mA
- Low Reverse Current – 2.0 μ A @ 10 V
- Continuous Forward Current – 500 mA
- Power Dissipation with Minimum Trace – 190 mW
- Very High Switching Speed – 4.0 ns @ 10 mA
- Low Capacitance – 12 pF @ 1.0 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

Markets

- Mobile Handsets
- MP3 Players
- Digital Camera and Camcorders
- Notebook PCs & PDAs
- GPS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	20	Vdc
Forward Continuous Current (DC)	I_F	500	mA
Non-Repetitive Peak Forward Surge Current	I_{FSM}	1.0	A
ESD Rating: Human Body Model Machine Model	ESD	Class 3B Class C	

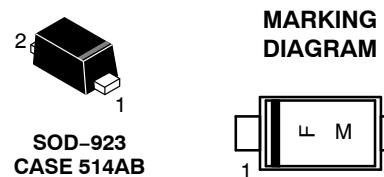
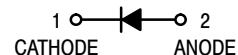
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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20 V SCHOTTKY BARRIER DIODE



MARKING
DIAGRAM



F = Specific Device Code
M = Month Code

ORDERING INFORMATION

Device	Package	Shipping†
NSR0620P2T5G	SOD-923 (Pb-Free)	2 mm Pitch 8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

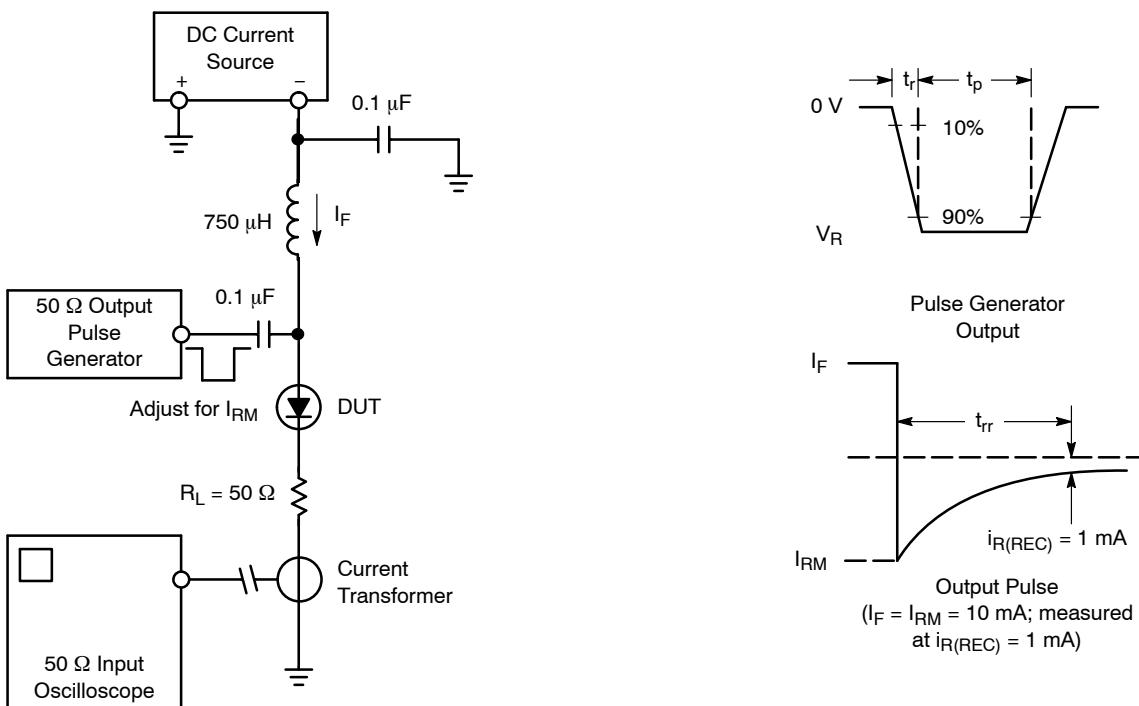
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$R_{\theta\text{JA}}$ P_D	520 190	$^\circ\text{C}/\text{W}$ mW
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$R_{\theta\text{JA}}$ P_D	175 570	$^\circ\text{C}/\text{W}$ mW
Junction Operating and Storage Temperature Range	T_J, T_{stg}	-55 to +125	$^\circ\text{C}$

1. Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single-sided. Operating to steady state.
2. Mounted onto a 4 in square FR-4 board 1 in sq. 1 oz. Cu 0.06" thick single-sided. Operating to steady state.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Leakage ($V_R = 10 \text{ V}$) ($V_R = 20 \text{ V}$)	I_R		2.0 9.0	10	μA
Forward Voltage ($I_F = 10 \text{ mA}$) ($I_F = 100 \text{ mA}$) ($I_F = 500 \text{ mA}$)	V_F		270 350 480	310 390 520	mV
Total Capacitance ($V_R = 1.0 \text{ V}$, $f = 1 \text{ MHz}$)	C_T		12		pF
Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}$, $I_R = 1.0 \text{ mA}$)	t_{rr}		4.0		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



1. DC Current Source is adjusted for a Forward Current (I_F) of 10 mA.
2. Pulse Generator Output is adjusted for a Peak Reverse Recovery Current I_{RM} of 10 mA.
3. Pulse Generator transition time $\ll t_{rr}$.
4. $I_{R(\text{REC})}$ is measured at 1 mA. Typically $0.1 \times I_{RM}$ or $0.25 \times I_{RM}$.
5. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

NSR0620P2

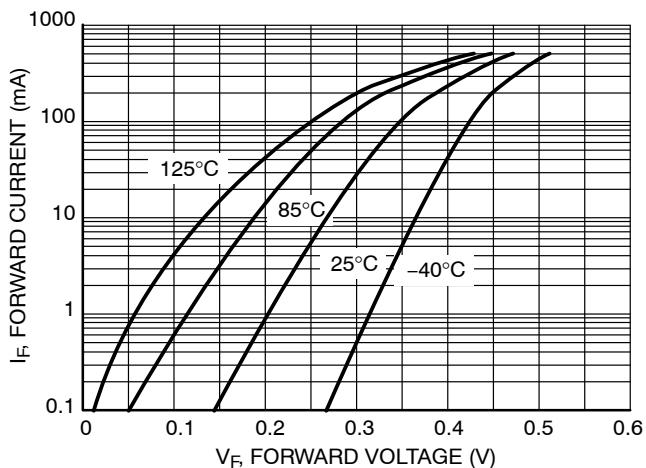


Figure 2.

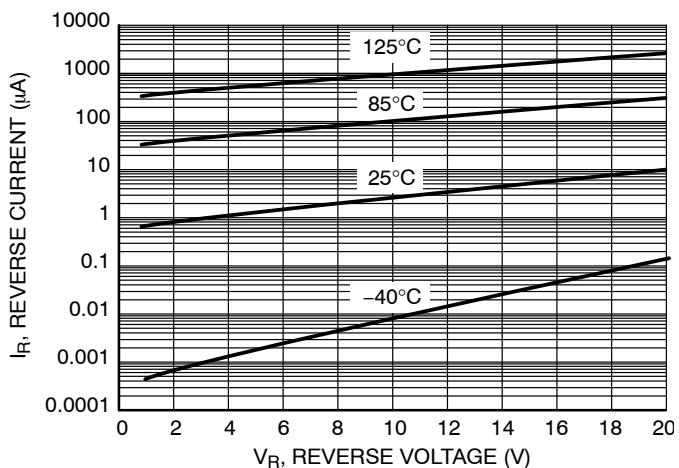


Figure 3.

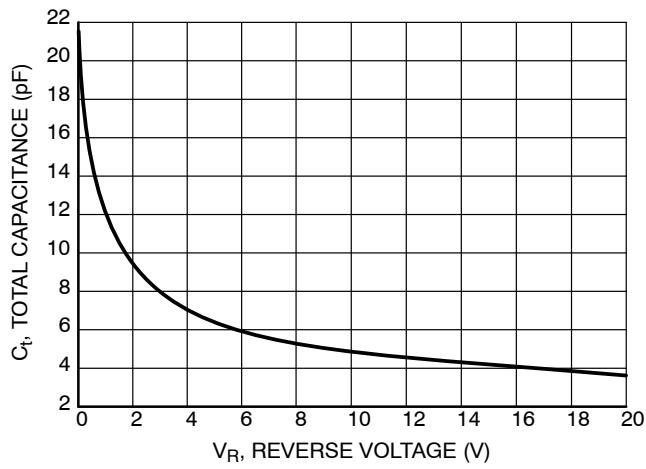
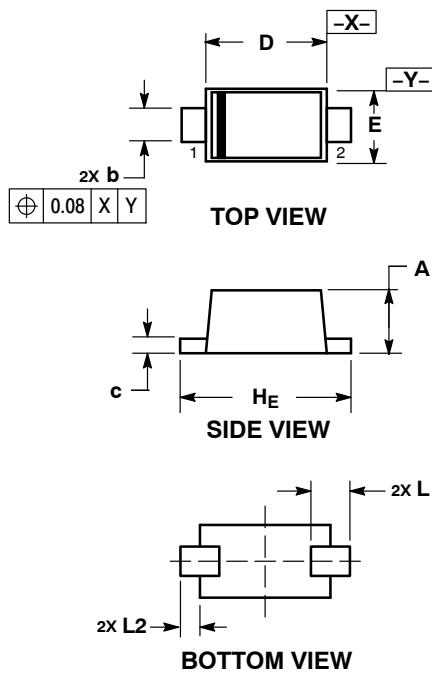


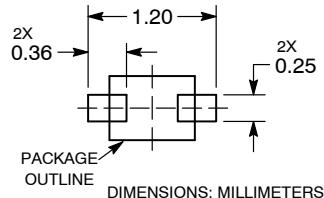
Figure 4.

PACKAGE DIMENSIONS

SOD-923
CASE 514AB
ISSUE C

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
E	0.55	0.60	0.65	0.022	0.024	0.026
HE	0.95	1.00	1.05	0.037	0.039	0.041
L	0.19 REF			0.007 REF		
L2	0.05	0.10	0.15	0.002	0.004	0.006

SOLDERING FOOTPRINT*



See Application Note AND8455/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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